# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



## **Quad 2-Input AND Gate**

### High-Performance Silicon-Gate CMOS

#### Features

- Outputs Source/Sink 24 mA
- 'ACT08 Has TTL Compatible Inputs

12

• These are Pb–Free Devices

13

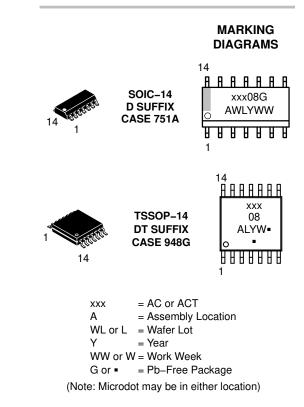
V<sub>CC</sub>

14



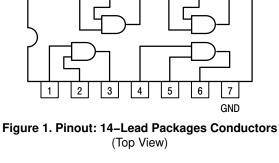
#### **ON Semiconductor®**

www.onsemi.com



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.



11

10

9

8

#### **MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \leq V_I \leq V_{CC} + 0.5$	V
V <sub>O</sub>	DC Output Voltage	(Note 1)	$-0.5 \leq V_O \leq V_{CC} + 0.5$	V
I <sub>IK</sub>	DC Input Diode Current		±20	mA
I <sub>OK</sub>	DC Output Diode Current		$\pm 50$	mA
I <sub>O</sub>	DC Output Sink/Source Current		$\pm 50$	mA
I <sub>CC</sub>	DC Supply Current per Output Pin		$\pm 50$	mA
I <sub>GND</sub>	DC Ground Current per Output Pin		$\pm 50$	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead temperature, 1 mm from Case for 10	) Seconds	260	°C
TJ	Junction temperature under Bias		+ 150	°C
$\theta_{JA}$	Thermal Resistance (Note 2)	SOIC TSSOP	125 170	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	SOIC TSSOP	125 170	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) harged Device Model (Note 5)	> 2000 > 200 > 1000	V
I <sub>Latch-Up</sub>	Latch–Up Performance Above V <sub>CC</sub> and	Below GND at 85°C (Note 6)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Io absolute maximum rating must be observed.
 The package thermal impedance is calculated in accordance with JESD51–7.
 Tested to EIA/JESD22–A114–A.

4. Tested to EIA/JESD22-A115-A.

Tested to JESD22-C101-A. 5.

6. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter			Тур	Max	Unit
	Oursely Matterna	Ϋ́AC	2.0	5.0	6.0	
V <sub>CC</sub>	Supply Voltage	ΆCΤ	4.5	5.0	5.5	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V <sub>CC</sub>	V
		V <sub>CC</sub> @ 3.0 V	-	150	-	ns/V
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	-	40	-	
		V <sub>CC</sub> @ 5.5 V	_	25	-	
	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V	-	10	-	
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	_	8.0	-	ns/V
TJ	Junction Temperature (PDIP)		_	_	140	°C
T <sub>A</sub>	Operating Ambient Temperature Range		-40	25	85	°C
I <sub>OH</sub>	Output Current – High		-	-	-24	mA
I <sub>OL</sub>	Output Current – Low		-	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1.  $V_{in}$  from 30% to 70%  $V_{CC}$ ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 2.  $V_{in}$  from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

#### **DC CHARACTERISTICS**

					74	AC	74AC	
						+25°C	T <sub>A</sub> = -40°C to +85°C	
Symbol	Parameter	Con	ditions	V <sub>CC</sub> (V)	Тур	Guar	anteed Limits	Unit
V <sub>IH</sub>	Minimum High Level Input Voltage	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	V	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V
V <sub>IL</sub>	Maximum Low Level Input Voltage	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> - 0.1 V		3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V
V <sub>OH</sub>	Minimum High Level Output Voltage	l <sub>OUT</sub> = -50 μA	A	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V
		V <sub>IN</sub> = V <sub>IL</sub> or V I <sub>OH</sub>	7 <sub>IH</sub> (Note 3) –12 mA –24 mA –24 mA	3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	v
V <sub>OL</sub>	Maximum Low Level Output Voltage	V <sub>IN</sub> = V <sub>IL</sub> or V I <sub>OL</sub>	7 <sub>IH</sub> (Note 3) 12 mA 24 mA 24 mA	3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	v
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>I</sub> = V <sub>CC</sub> , GN	D	5.5	-	±0.1	±1.0	μA
I <sub>OLD</sub>	Minimum Dynamic (Note 4)	V <sub>OLD</sub> = 1.65 \	/ Max	5.5	-	-	75	mA
I <sub>OHD</sub>	Output Current	V <sub>OHD</sub> = 3.85	V Min	5.5	-	-	-75	mA
I <sub>CC</sub>	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or	GND	5.5	-	4.0	40	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTE: I<sub>IN</sub> and I<sub>CC</sub> @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

All outputs loaded; thresholds on input associated with output under test.
 Maximum test duration 2.0 ms, one output loaded at a time.

#### **AC CHARACTERISTICS**

				74AC		74	AC		
		V <sub>CC</sub> (V)	-	₄ = +25° L = 50 p		to +	-40°C 85°C 50 pF		Fig.
Symbol	Parameter	(Note5)	Min	Тур	Max	Min	Max	Unit	No.
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	1.5 1.5	7.5 5.5	9.5 7.5	1.0 1.0	10.0 8.5	ns	3–5
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	1.5 1.5	7.0 5.5	8.5 7.0	1.0 1.0	9.0 7.5	ns	3–5

5. Voltage Range 3.3 V is 3.3 V ±0.3 V. Voltage Range 5.0 V is 5.0 V ±0.5 V.

#### **DC CHARACTERISTICS**

				74ACT T <sub>A</sub> = +25°C		74ACT		
			V <sub>cc</sub>			T <sub>A</sub> = –40°C to +85°C		
Symbol	Parameter	Conditions	(V)	Тур	Guar	anteed Limits	Unit	
V <sub>IH</sub>	Minimum High Level	V <sub>OUT</sub> = 0.1 V	4.5	1.5	2.0	2.0	V	
	Input Voltage	or $V_{CC}$ – 0.1 V	5.5	1.5	2.0	2.0	v	
V <sub>IL</sub>	Maximum Low Level	V <sub>OUT</sub> = 0.1 V	4.5	1.5	0.8	0.8	V	
	Input Voltage	or $V_{CC}$ – 0.1 V	5.5	1.5	0.8	0.8	v	
V <sub>OH</sub>	Minimum High Level	I <sub>OUT</sub> = -50 μA	4.5	4.49	4.4	4.4	V	
	Output Voltage		5.5	5.49	5.4	5.4	v	
		$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 6)}$					V	
		–24 mA	4.5	-	3.86	3.76		
		–24 mA	5.5	-	4.86	4.76		
V <sub>OL</sub>	Maximum Low Level	I <sub>OUT</sub> = 50 μA	4.5	0.001	0.1	0.1	V	
	Output Voltage		5.5	0.001	0.1	0.1	v	
		$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 6)}$					V	
		24 mA	4.5	-	0.36	0.44		
		24 mA	5.5	-	0.36	0.44		
I <sub>IN</sub>	Maximum Input Leakage Current	$V_{I} = V_{CC}, GND$	5.5	-	±0.1	±1.0	μA	
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	$V_{I} = V_{CC} - 2.1 V$	5.5	0.6	-	1.5	mA	
I <sub>OLD</sub>	Minimum Dynamic (Note 7)	V <sub>OLD</sub> = 1.65 V Max	5.5	-	-	75	mA	
I <sub>OHD</sub>	Output Current	V <sub>OHD</sub> = 3.85 V Min	5.5	-	-	-75	mA	
I <sub>CC</sub>	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5	-	4.0	40	μA	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
6. All outputs loaded; thresholds on input associated with output under test.
7. Maximum test duration 2.0 ms, one output loaded at a time.

#### **AC CHARACTERISTICS**

				74ACT		74 <b>A</b>	СТ		
		V <sub>CC</sub> (V)		₄ = +25° ∟ = 50 p		T <sub>A</sub> = - to +8 C <sub>L</sub> = \$	85°C		Fig.
Symbol	Parameter	(Note 8)	Min	Тур	Max	Min	Max	Unit	No.
t <sub>PLH</sub>	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–5
t <sub>PHL</sub>	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–5

8. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

#### CAPACITANCE

Symbol	Parameter	Test Conditions	Value Typ	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 5.0 V	4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 5.0 V$	20	pF

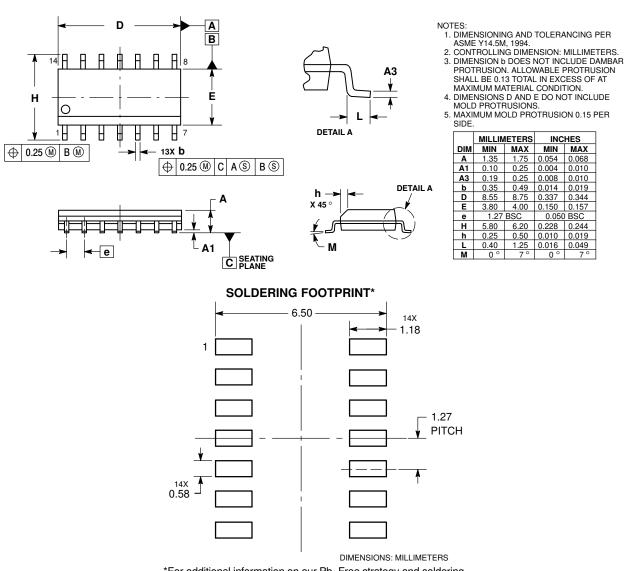
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC74AC08DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74AC08DR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74AC08DTR2G	TSSOP-14 (Pb-Free)	2500 / Tape & Reel
MC74ACT08DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74ACT08DR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74ACT08DTR2G	TSSOP-14 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

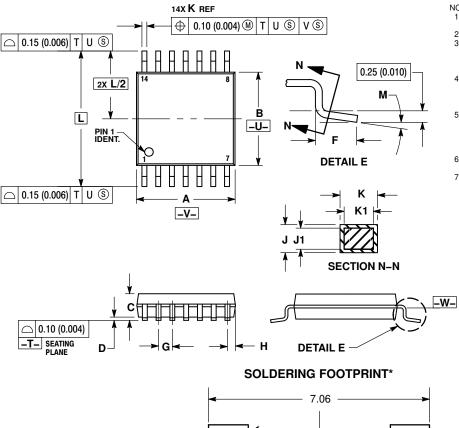
SOIC-14 NB CASE 751A-03 ISSUE K



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

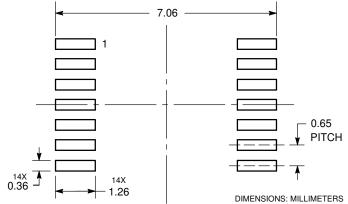
TSSOP-14 CASE 948G **ISSUE B** 



NOTES:

- NOTES:
   DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: MILLIMETER.
   DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
   DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED 0.25
- OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- (0.010) PEH SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. TERMINAL NUMBERS ARE SHOWN FOR DEFEDENCE ONLY 5.
- 6.
- TENNINAL NOWDERS ARE SHOWN FOR REFERENCE ONLY.
   DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE W–.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
Н	0.50	0.60	0.020	0.024	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
κ	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40		0.252 BSC		
М	0 °	8 °	0 °	8 °	



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the use are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual properly. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for uses as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC may claim alloges that SCILLC and its personal injury or death associated with such unintended or unauthorized use, even if such c

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative